

05/27/2008

**REPLY UNDER 37 CFR 1.116  
EXPEDITED PROCEDURE  
TECHNOLOGY CENTER 1700**

Attorney's Docket No. 015675.P568

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application for:

**Bernard Beaumont, et al.**

Application No. 10/522,397

Filed: October 21, 2005

For: **METHOD FOR PRODUCING BY  
VAPOUR-PHASE EPITAXY A GALLIUM  
NITRIDE FILM WITH LOW DEFECT  
DENSITY**

Examiner: Marissa W. Chaet

Art Unit: 1791

Confirmation No.: 6314

**AMENDMENT AND RESPONSE TO FINAL OFFICE ACTION**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Madam:

In response to the Final Office Action dated March 18, 2008, Applicants submit the following amendments and remarks: